



NCE N-Channel Super Trench Power MOSFET

Description

The NCEP60T20 uses Super Trench technology that is uniquely optimized to provide the most efficient high frequency switching performance. Both conduction and switching power losses are minimized due to an extremely low combination of $R_{DS(ON)}$ and Q_g . This device is ideal for high-frequency switching and synchronous rectification.

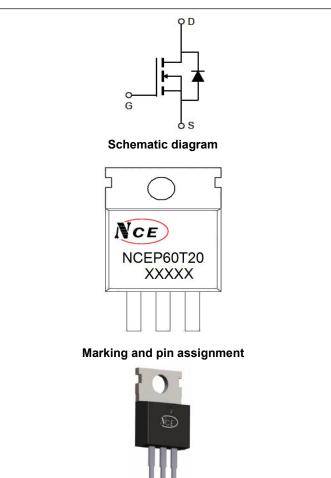
General Features

- V_{DS} =60V,I_D =200A R_{DS(ON)}=1.8mΩ (typical) @ V_{GS}=10V
- Excellent gate charge x R_{DS(on)} product
- Very low on-resistance RDS(on)
- 175 °C operating temperature
- Pb-free lead plating
- 100% UIS tested

Application

- DC/DC Converter
- Ideal for high-frequency switching and synchronous rectification

100% UIS TESTED! 100% ΔVds TESTED!



D TO-220-3L top view

G

Package Marking and Ordering Information

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
NCEP60T20	NCEP60T20	TO-220-3L	-	-	-

Absolute Maximum Ratings (Tc=25°Cunless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	Vds	60	V
Gate-Source Voltage	Vgs	±20	V
Drain Current-Continuous (Silicon Limited)	Ι _D	200	A
Drain Current-Continuous(Tc=100 ℃)	l₀(100℃)	150	А
Pulsed Drain Current	I _{DM}	800	A
Maximum Power Dissipation	PD	255	W
Derating factor		1.7	W/℃
Single pulse avalanche energy ^(Note 1)	Eas	2000	mJ
Operating Junction and Storage Temperature Range	TJ,TSTG	-55 To 175	°C







Thermal Characteristic

Thermal Resistance, Junction-to-Case

°C/W

0.59

Electrical Characteristics (Tc=25 $^{\circ}$ C unless otherwise noted)

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Off Characteristics	· · ·		1			
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V I _D =250µA	60		-	V
Zero Gate Voltage Drain Current	IDSS	V _{DS} =60V,V _{GS} =0V	-	-	1	μA
Gate-Body Leakage Current	I _{GSS}	V_{GS} =±20V, V_{DS} =0V	-	-	±100	nA
On Characteristics	· · ·		•			
Gate Threshold Voltage	V _{GS(th)}	V _{DS} =V _{GS} ,I _D =250µA	2.2	3.0	4.0	V
Drain-Source On-State Resistance	R _{DS(ON)}	V _{GS} =10V, I _D =100A	-	1.8	2.2	mΩ
Forward Transconductance	g fs	V _{DS} =10V,I _D =100A	-	60	-	S
Dynamic Characteristics						
Input Capacitance	Clss		-	9200	-	PF
Output Capacitance	Coss	V _{DS} =30V,V _{GS} =0V,	-	1900	-	PF
Reverse Transfer Capacitance	C _{rss}	F=1.0MHz	-	61	-	PF
Switching Characteristics (Note 2)	· · ·					
Turn-on Delay Time	t _{d(on)}		-	23	-	nS
Turn-on Rise Time	tr	V _{DD} =30V,I _D =100A	-	19	-	nS
Turn-Off Delay Time	t _{d(off)}	V_{GS} =10V, R_{G} =4.7 Ω	-	58	-	nS
Turn-Off Fall Time	t _f		-	14	-	nS
Total Gate Charge	Qg)/ _20)/ L _100A	-	130		nC
Gate-Source Charge	Qgs	V _{DS} =30V,I _D =100A, V _{GS} =10V	-	40.6		nC
Gate-Drain Charge	Q _{gd}	VGS-TUV	-	23.9		nC
Drain-Source Diode Characteristics	· · ·		1			
Diode Forward Voltage	V _{SD}	V _{GS} =0V,I _S =200A	-		1.2	V
Diode Forward Current	ls		-	-	120	A
Reverse Recovery Time	t _{rr}	$T_J = 25^{\circ}C, I_F = I_S$	-	67		nS
Reverse Recovery Charge	Qrr	di/dt = 100A/µs	-	112		nC

Rejc

Notes:

1. EAS condition : Tj=25 $^\circ \!\! \mathbb{C}$,V_DD=30V,V_G=10V,L=0.5mH,Rg=25 Ω

2. Guaranteed by design, not subject to production

3. These curves are based on the junction-to-case thermal impedance which is measured with the device mounted to a large heats in k, assuming a maximum junction temperature of $TJ(MAX)=175^{\circ}$ C. The SOA curve provides a single pulse rating.

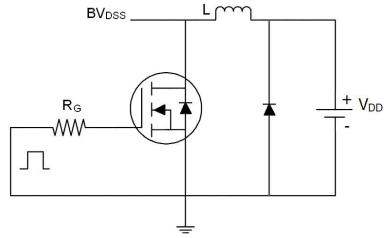


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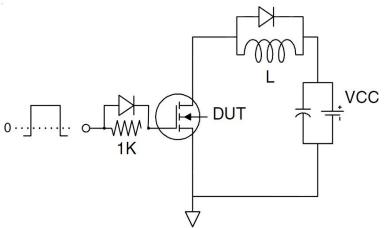
Pb Free Product



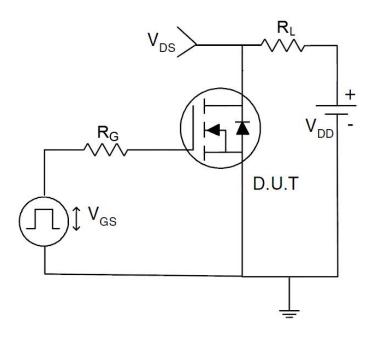
Test Circuit 1) E_{AS} test Circuit



2) Gate charge test Circuit



3) Switch Time Test Circuit





75

80

1.0

100

120

140

2.0

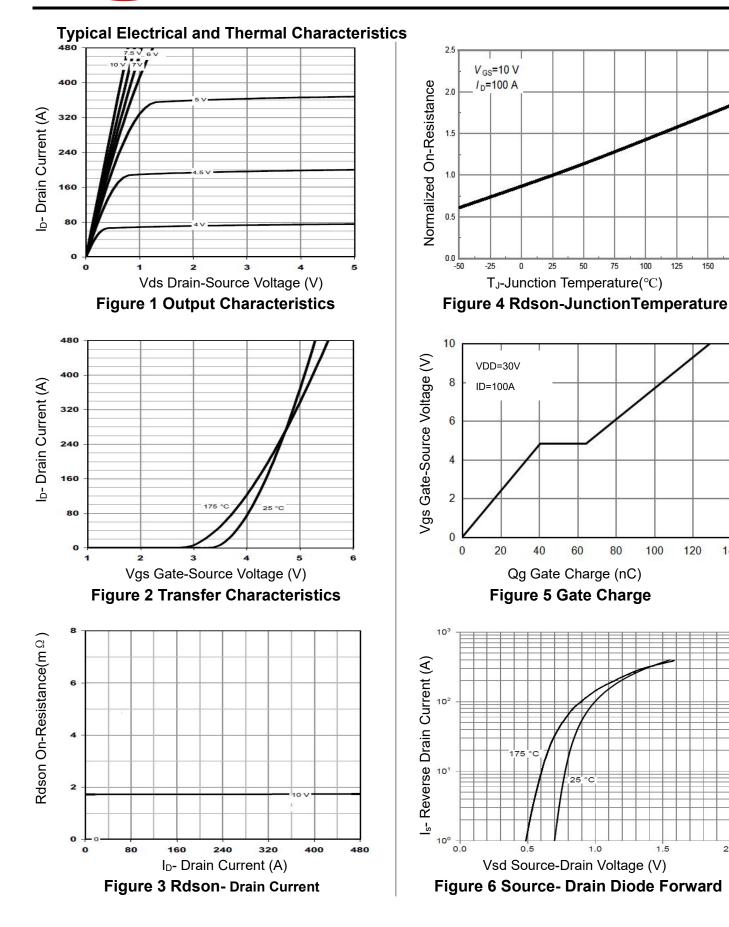
100

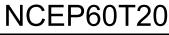
125

150

175







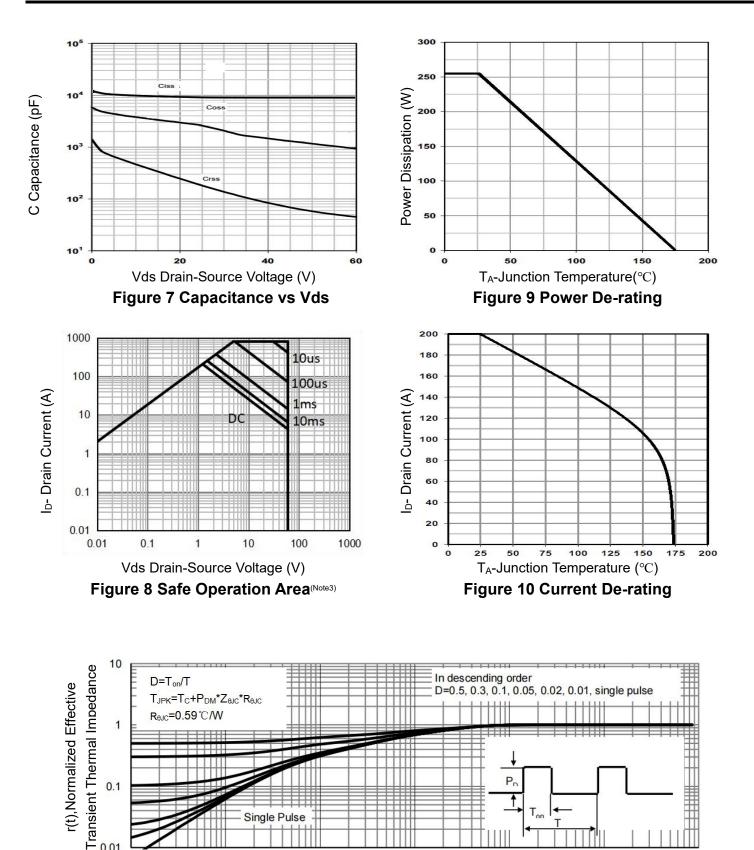
1.5



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Single Pulse

10

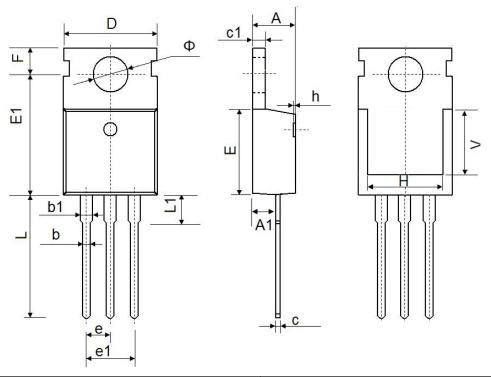


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TO-220-3L(C) Package Information



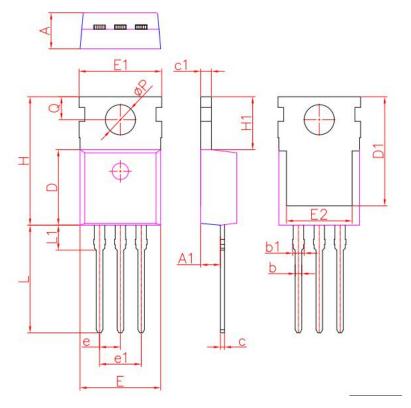
Symbol	Dimensions	In Millimeters	Dimensions In Inches			
Symbol	Min.	Max.	Min.	Max.		
A	4.400	4.600	0.173	0.181		
A1	2.250	2.550	0.089	0.100		
b	0.710	0.910	0.028	0.036		
b1	1.170	1.370	0.046	0.054		
С	0.330	0.650	0.013	0.026		
c1	1.200	1.400	0.047	0.055		
D	9.910	10.250	0.390	0.404		
E	8.9500	9.750	0.352	0.384		
E1	12.650	12.950	0.498	0.510		
е	2.540	TYP.	0.100 TYP.			
e1	4.980	5.180	0.196	0.204		
F	2.650	2.950	0.104	0.116		
Н	7.900	8.100	0.311	0.319		
h	0.000	0.300	0.000	0.012		
L	12.900	13.400	0.508	0.528		
L1	2.850	3.250	0.112	0.128		
V	6.900	6.900 REF.		0.276REF.		
Ф	3.400	3.800	0.134	0.150		







TO-220-3L(E) Package Information



		220	
DIM.	MIN.	NOM.	MAX.
А	4.20	4.40	4.60
A1	2.25	2.40	2.55
ь	0.70	0.80	0.90
Ь1	1.17	1.27	1.37
с	0.33	0.50	0.65
c1	1.20	1.30	1.40
D	8.95	9.20	9.75
D1	13.10	13.30	13.50
Е	9.74	9.84	10.04
E1	9.91	10.08	10.25
E2	7.90	8.00	8.10
е	54	2.54BSC	5
e1	5.08BSC		
н	15.45	15.65	15.85
H1	6.30	6.45	6.60
L	12.90	13.13	13.40
L1	2.85	3.05	3.25
Q	2.65	2.80	2.95
ØP	3.40	3.68	3.80







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